



Atty. Docket No.:
H0004667
(1139.1137101)

Serial No.:
10/612,660

LIST OF PATENTS AND PUBLICATIONS FOR
APPLICANT'S INFORMATION
DISCLOSURE STATEMENT

Applicant: Bo Su Chen et al.

Filing Date:

July 2, 2003

Group Art:

unknown

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July 2, 2003	unknown

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EXAMINER: *Michelle R. Connolly-Lushine* DATE CONSIDERED: *2/22/06*

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